

# Parameter extraction from electromagnetic eigenmode simulations of multimodal cavities using MFEM

Christopher Eyre, Ryan Camacho, Keith Cartwright

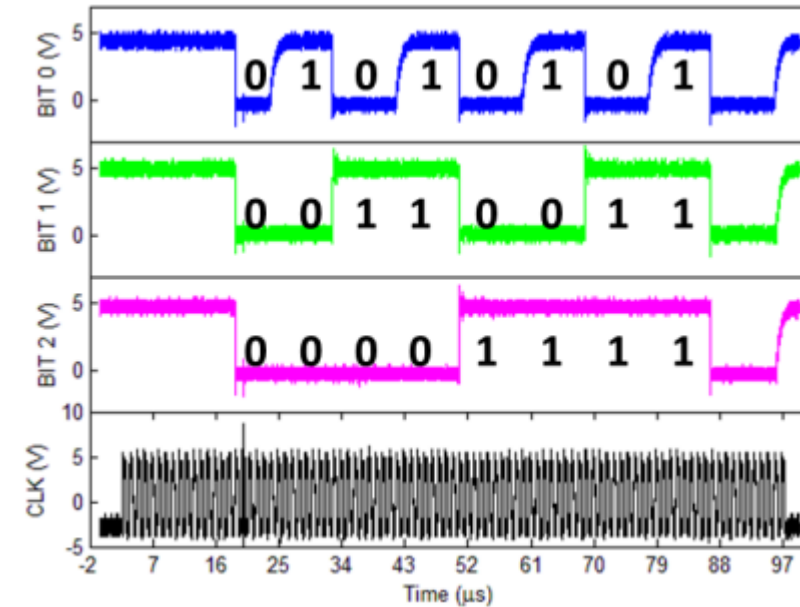
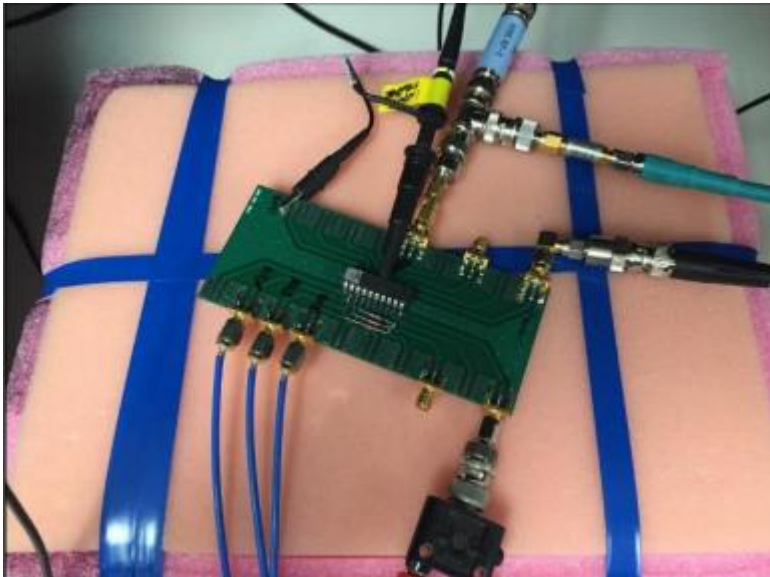


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# Motivation



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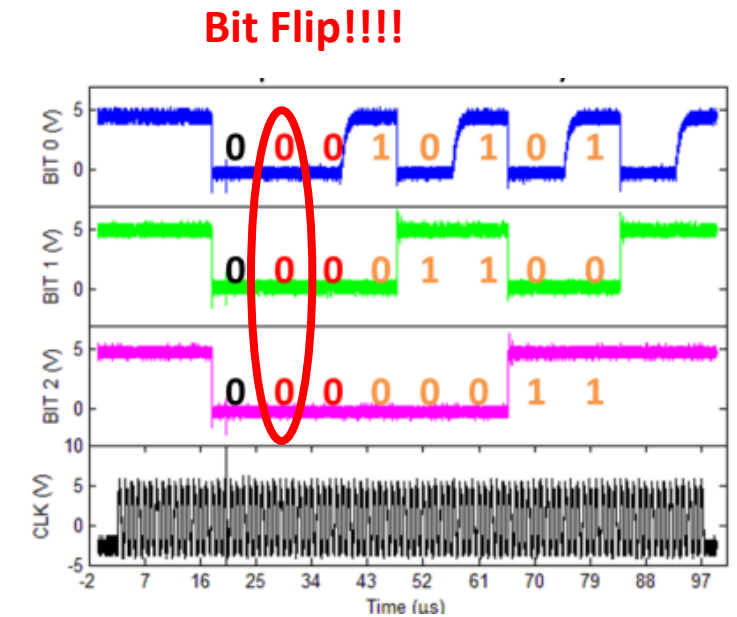
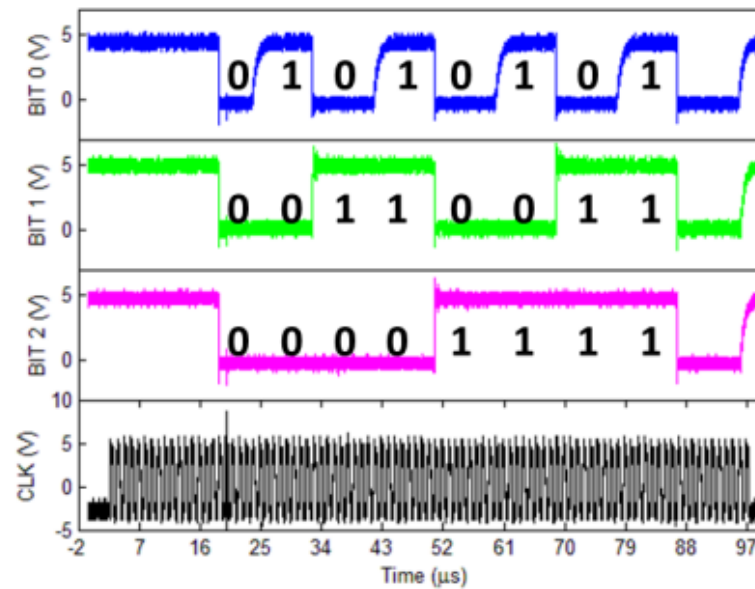
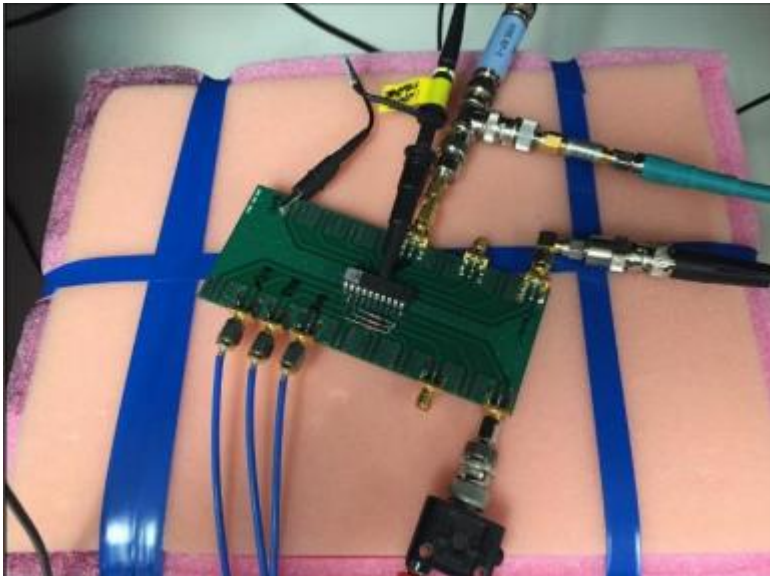
Guillette, D., & Clarke, T. (2019). *Intentional electromagnetic irradiation on a microcontroller: Review of upset variation with respect to chip instance*. Air Force Research Lab.

# Motivation



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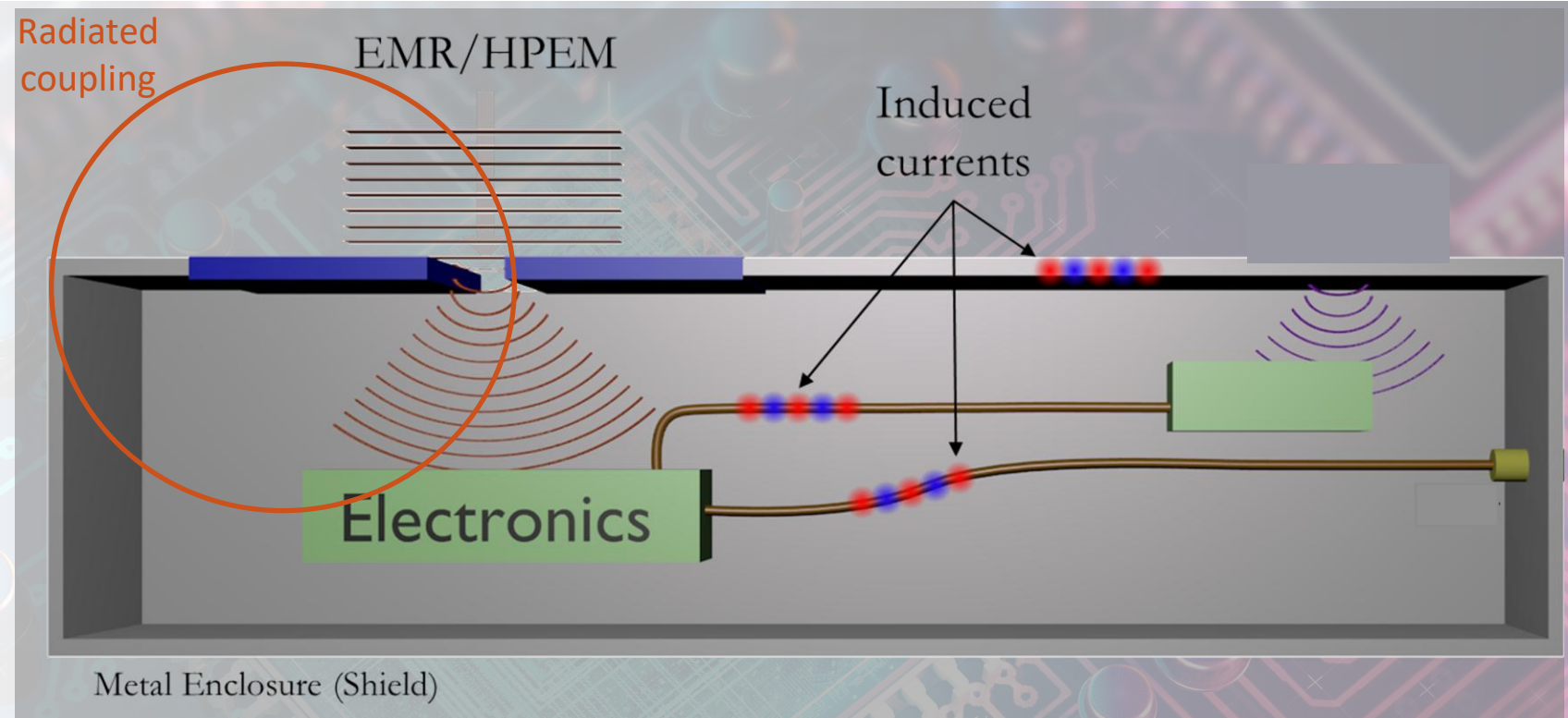


# We want to model circuits that are inside cavities



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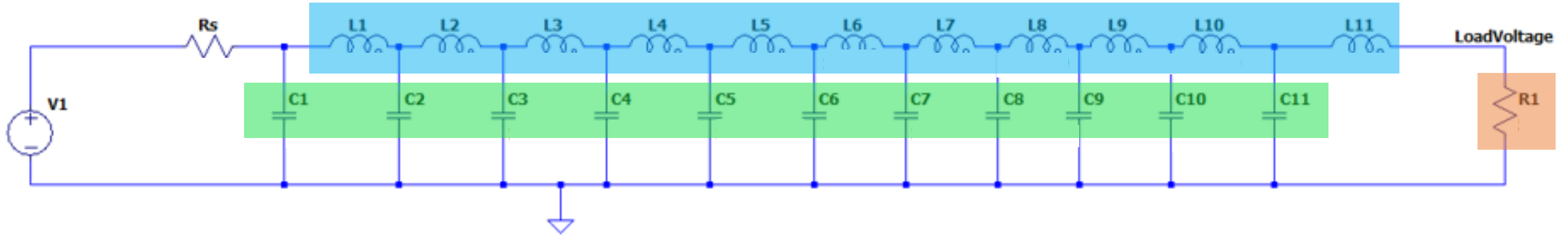
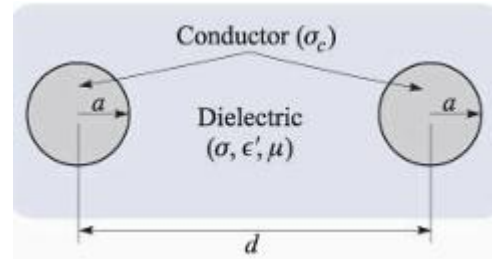


# Circuit simulator for Transmission line



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Circuit Modeling done in LTSPICE (M. Engelhardt, LTspice/SwitcherCAD III, Linear Technology Corporation, 2024)  
Two wire cross section from Hayt, William, and John Buck. "Engineering electromagnetics." (2012). 5

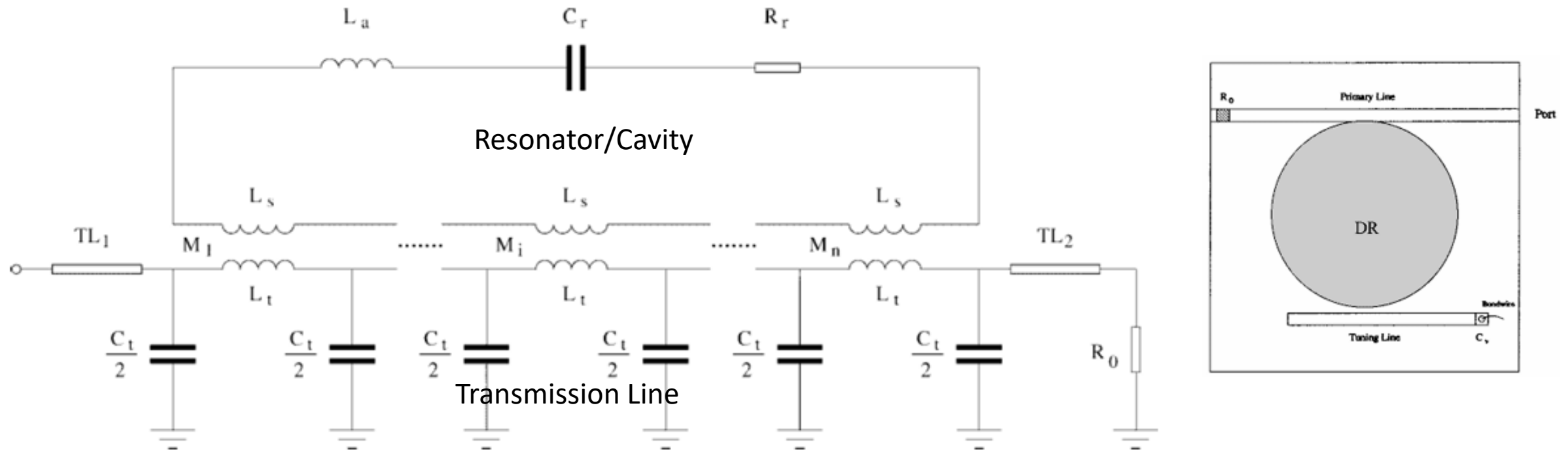
# Distributed Coupling



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$$\Phi_m = \iint_{\Sigma} \mathbf{B} \cdot d\mathbf{S} \quad \Phi_d = \iint_{\Sigma} \mathbf{D} \cdot d\mathbf{S} \quad I = 2\pi f_r \Phi_d \quad M = \Phi_m / I \quad L_r = W / I^2 \quad C_r = \frac{1}{(2\pi f_r)^2 L_r}$$



X. Xu and R. Sloan, "Distributed Coupling Model of the Dielectric Resonator to Microstrip Line" IEEE Microwave and Guided Wave Letters, 9, 348-350, 1999.

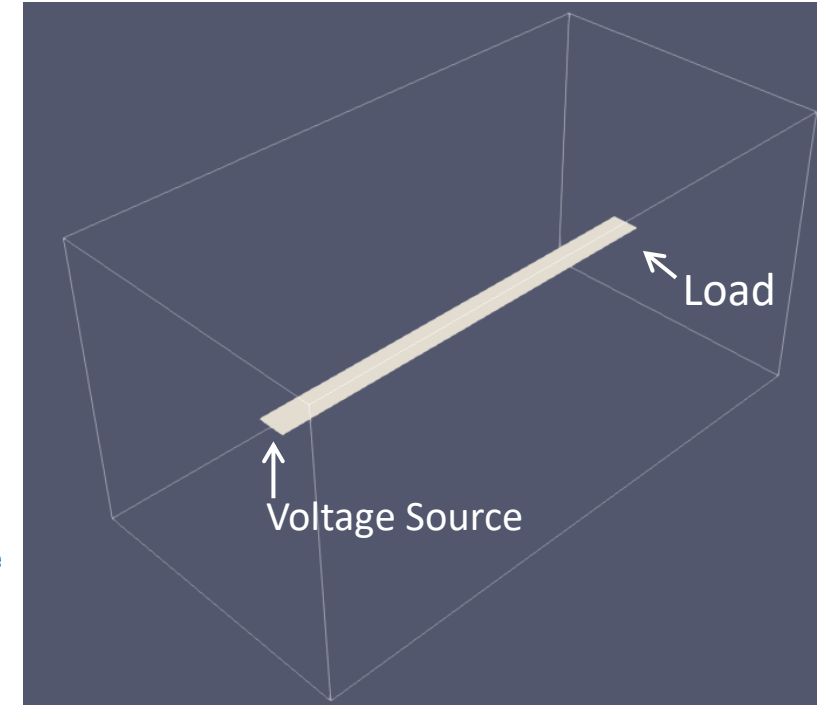
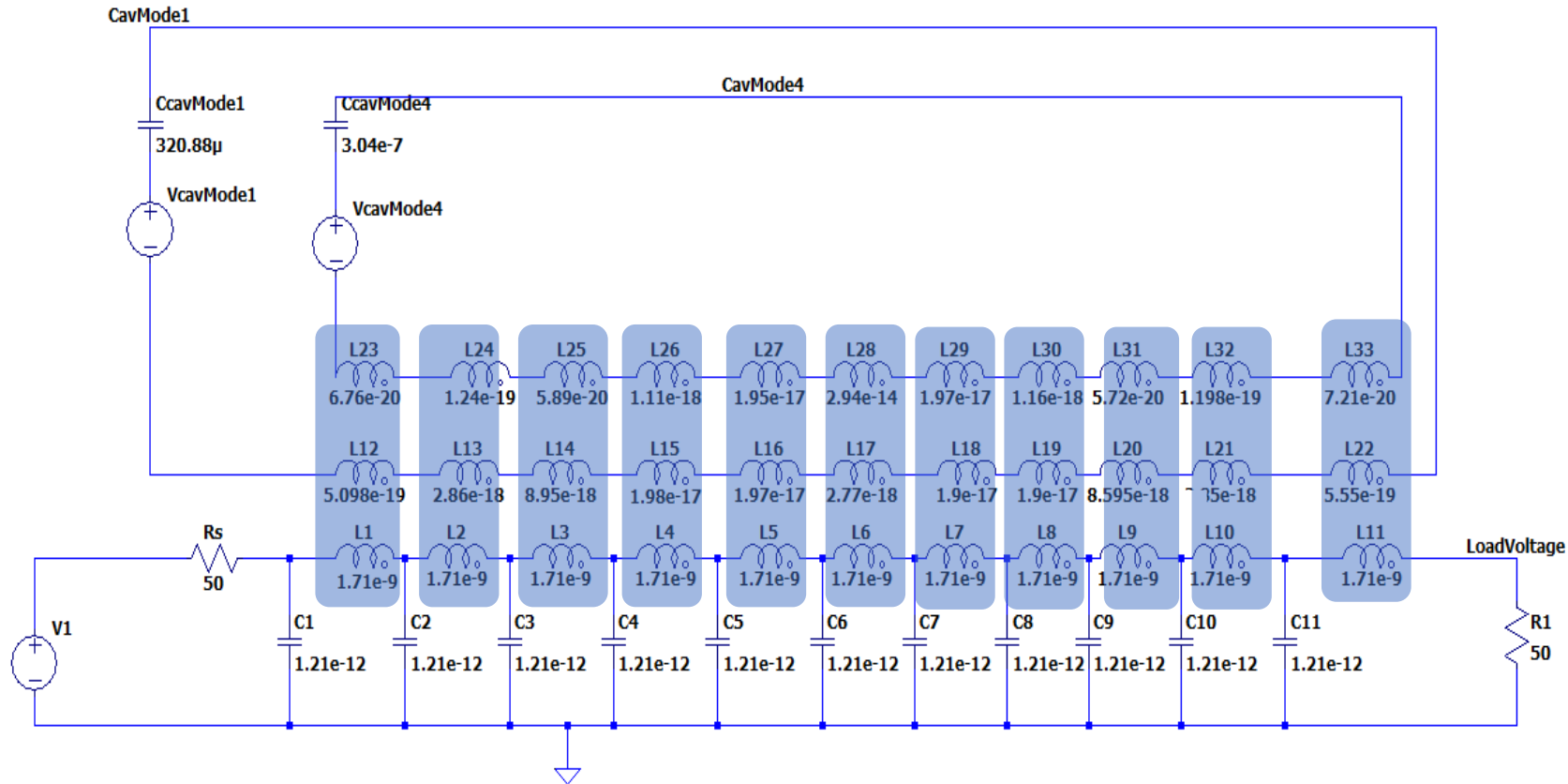
X. Xu and R. Sloan, "Improved tuning prediction for the microstrip coupled dielectric resonator using distributed coupling," in IEEE Transactions on Microwave Theory and Techniques, vol. 49, no. 3, pp. 553-555, March 2001

# Modelling Coupling in a Circuit Simulator



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Circuit Modeling done in LTSPICE (M. Engelhardt, LTspice/SwitcherCAD III, Linear Technology Corporation, 2024)

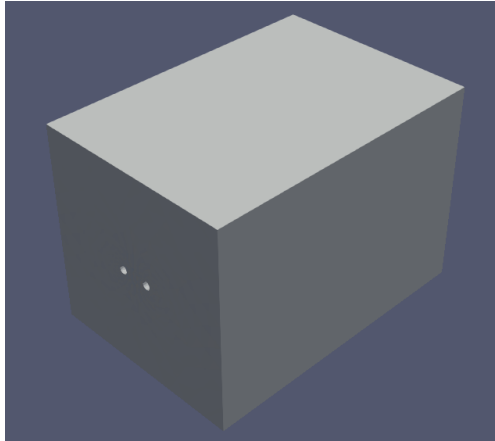


# Eigenmodes from MFEM example 13



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$$\nabla \times \nabla \times E = k^2 E$$

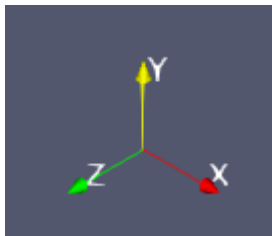
$$\omega = ck = c\sqrt{\lambda}$$

Magnitude

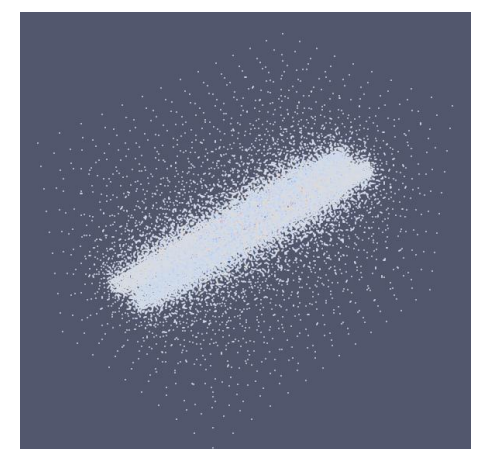
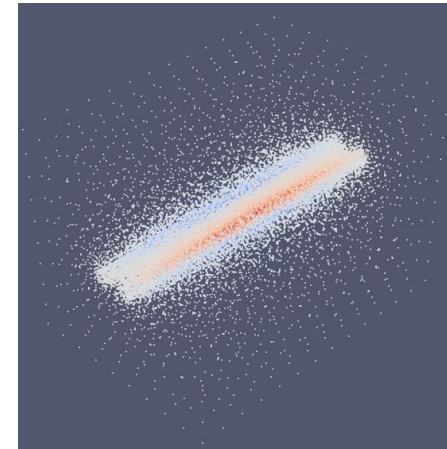
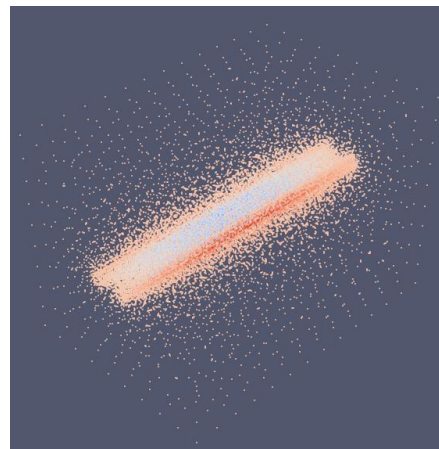
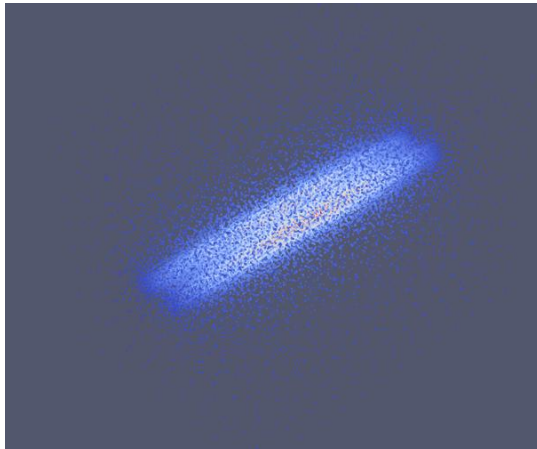
Efield in X

Efield in Y

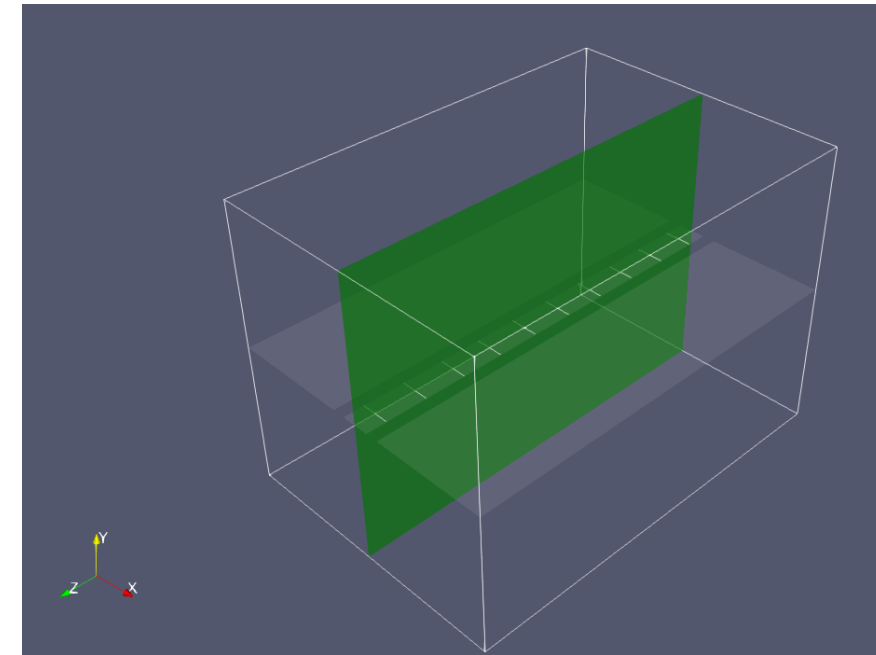
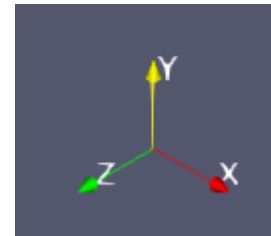
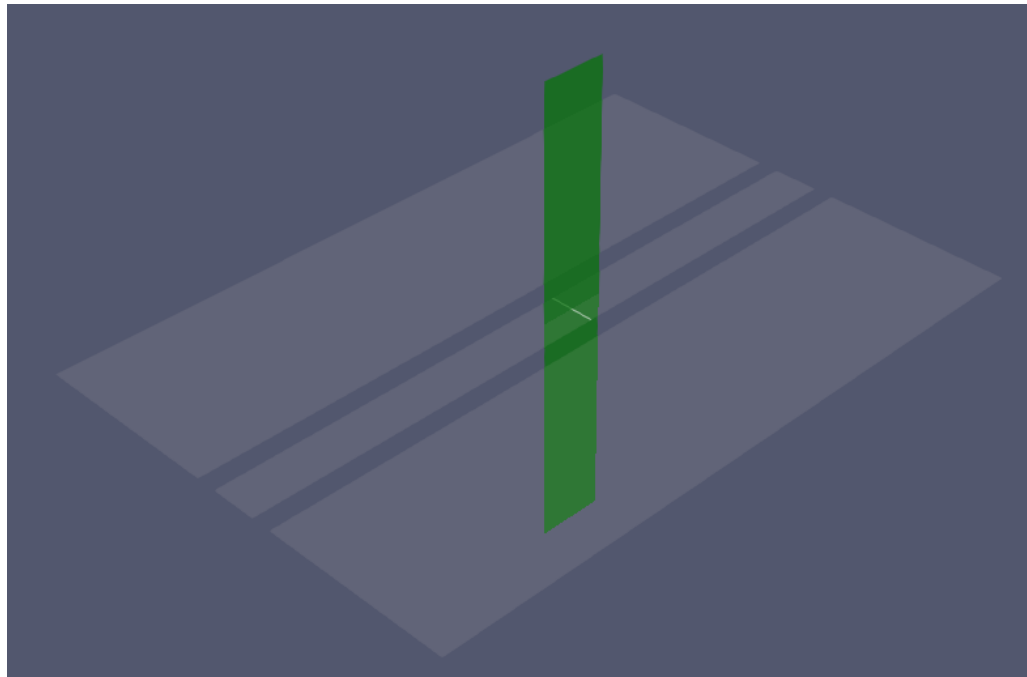
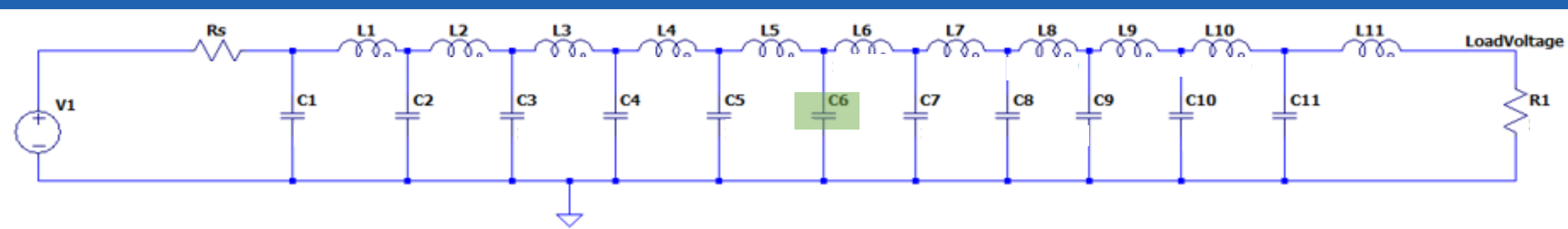
Efield in Z



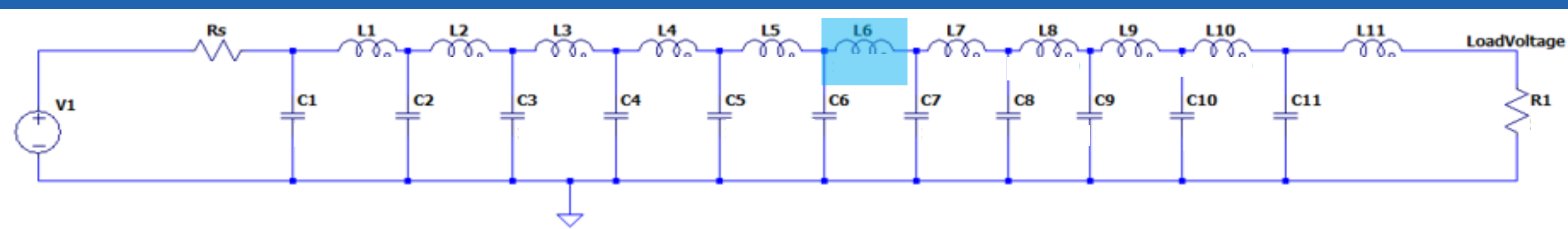
Mode 0 –  
Eigenfrequency:  
14.9e+6 Hz







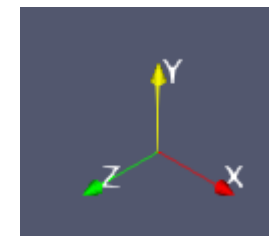
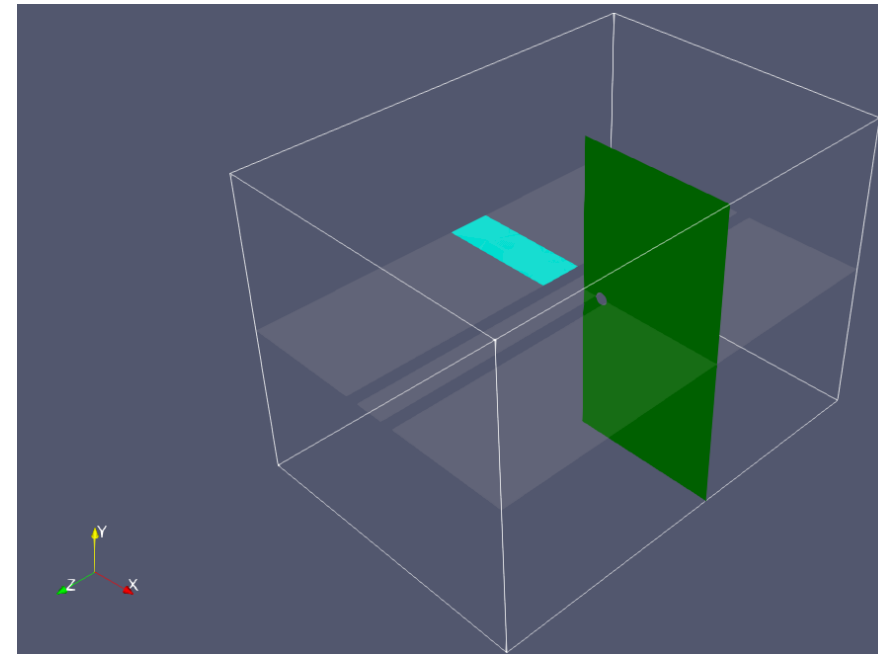
$$\text{Capacitance} = \frac{Q}{V} \rightarrow \frac{\iint \epsilon \mathbf{E} \cdot d\mathbf{S} / L}{\oint \mathbf{E} \cdot d\boldsymbol{\ell}}$$



$$\text{Mutual Inductance} = \frac{\Phi_m}{I}$$

$$\rightarrow \frac{\iint \mathbf{B} \cdot d\mathbf{S} / L}{\oint \mathbf{B} \cdot d\boldsymbol{\ell}} \rightarrow \frac{\iint \mathbf{B} \cdot d\mathbf{S} / L}{i\omega\mu_0\epsilon \iint \mathbf{E} \cdot d\mathbf{A}}$$

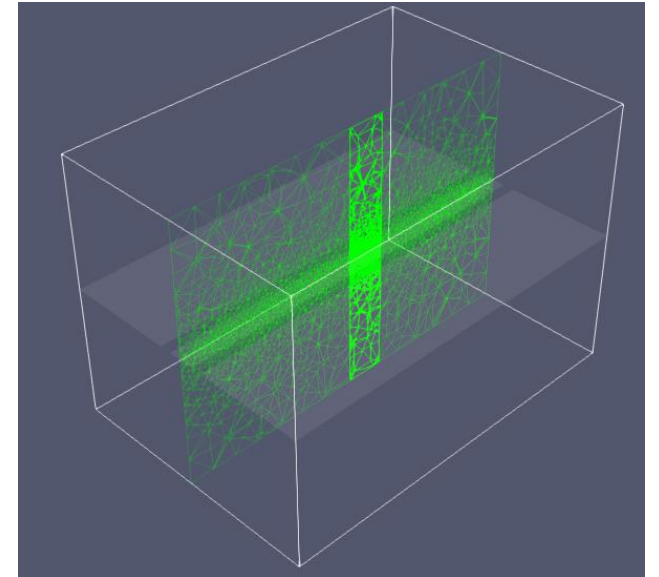
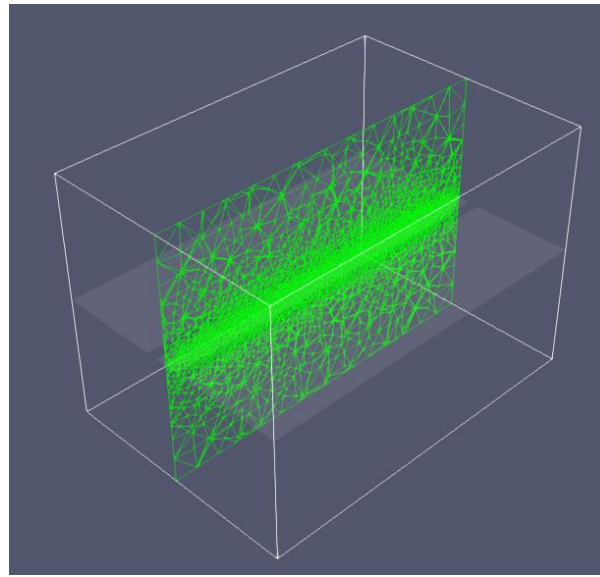
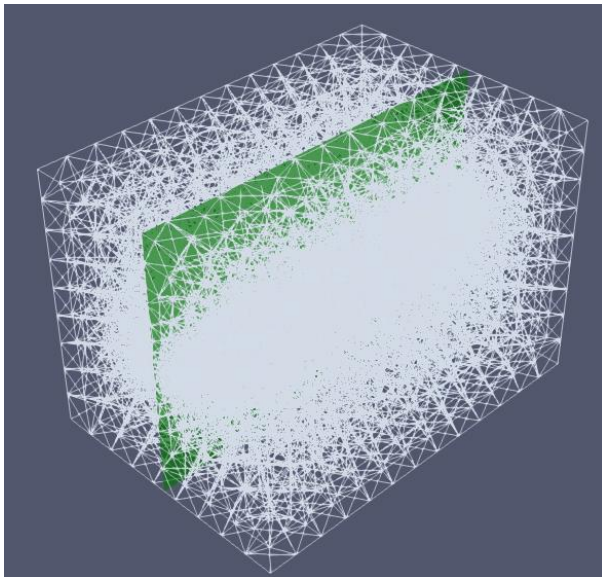
$$\mathbf{B} = \frac{-j}{\omega} \nabla \times \mathbf{E}$$



# Integration Attempts



- Monte Carlo integration
  - Takes around 15 minutes per integral with 10,000 points on me
- Quadrature integration (my implementation)
  - Takes about 2 minutes per integral
- (Potential alternative) intrules\_cut methods provided by MFEM

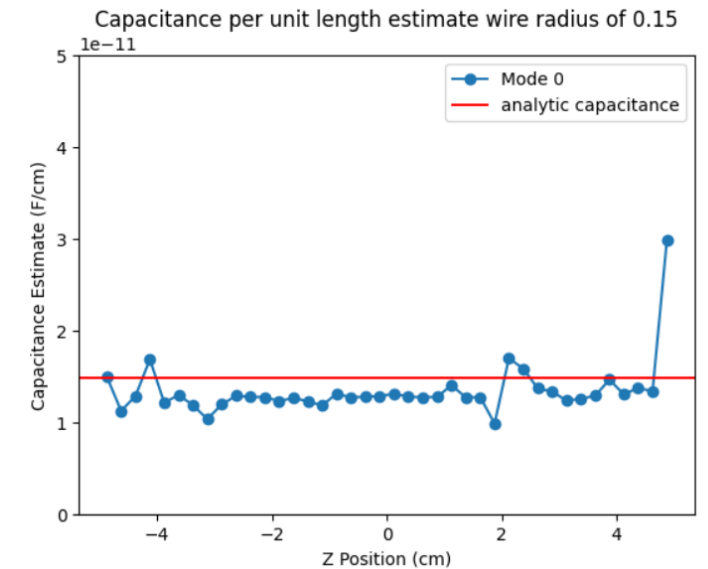
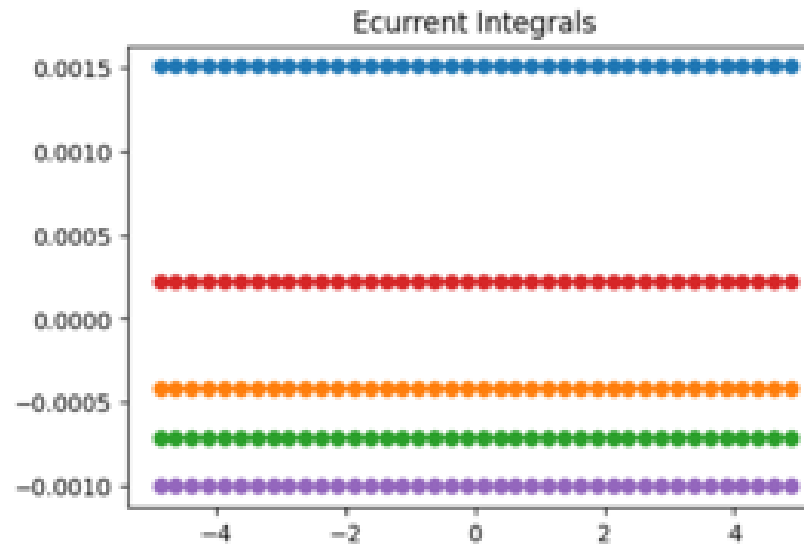
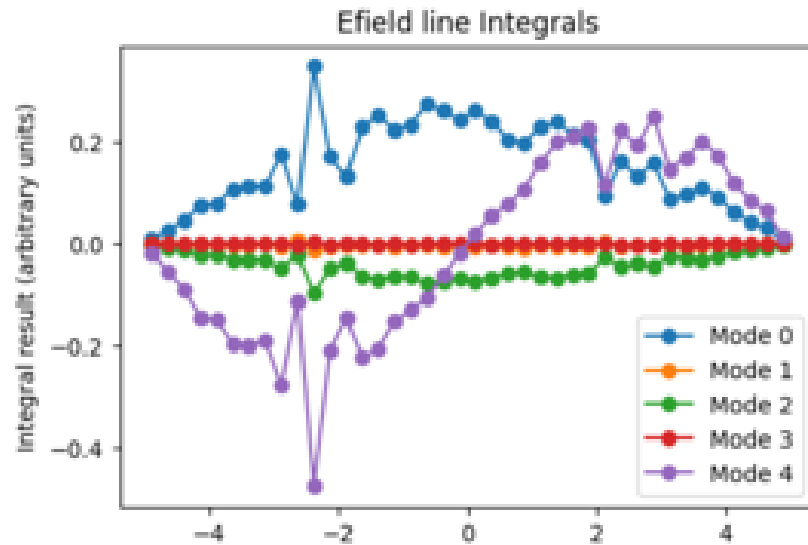


# Results – Capacitance



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$$\text{Capacitance} = \frac{Q}{V} \rightarrow \frac{\iint \epsilon \mathbf{E} \cdot d\mathbf{S} / L}{\oint \mathbf{E} \cdot d\boldsymbol{\ell}}$$

Analytic Capacitance: 2.531944e-11

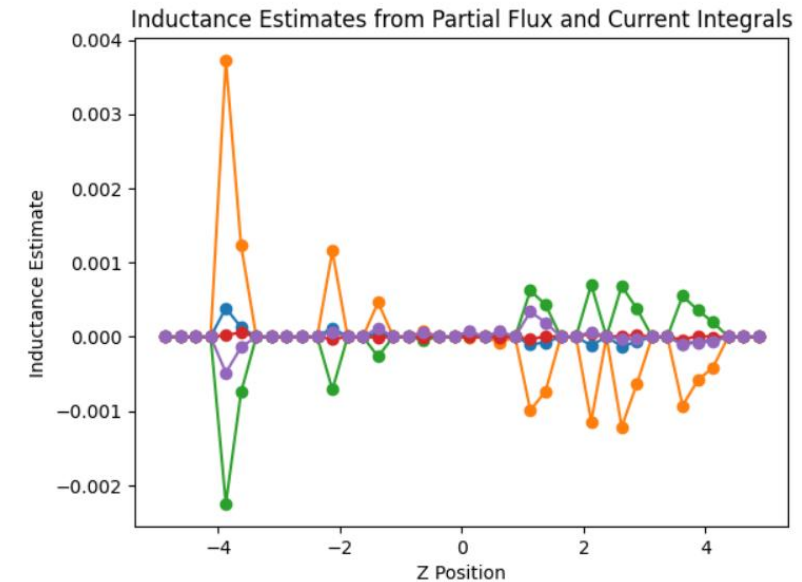
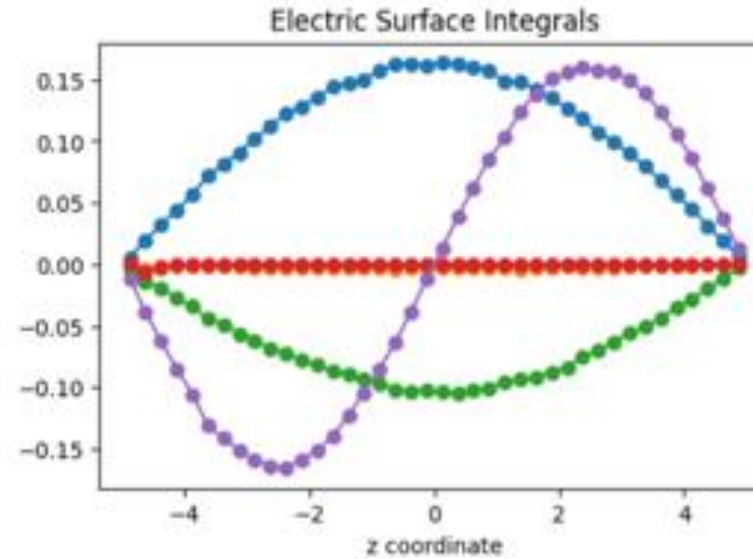
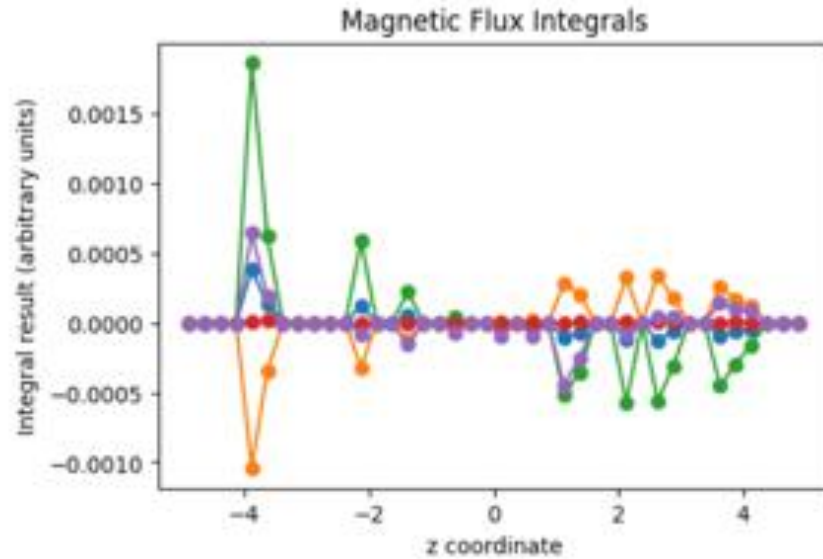


# Results – Inductance



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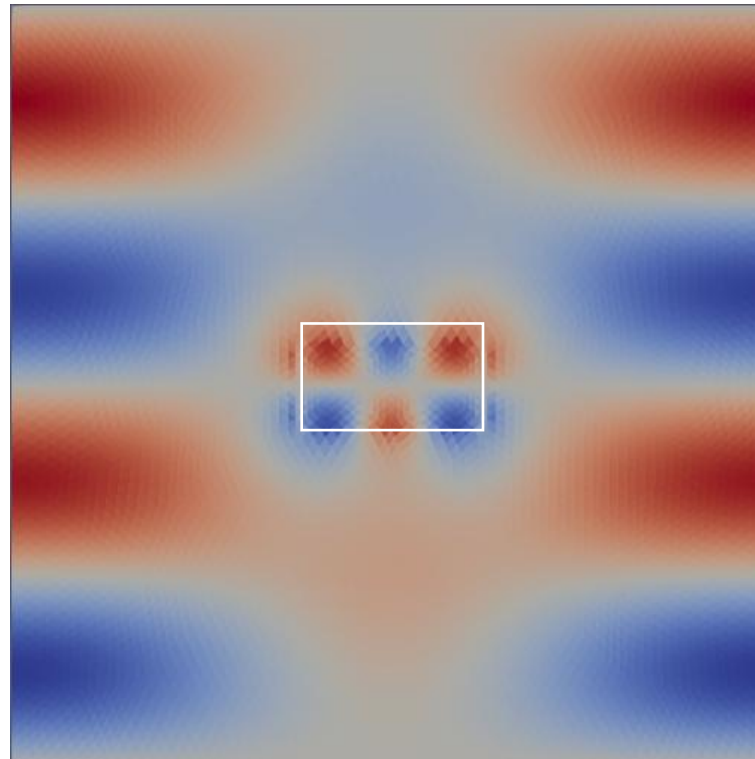


$$\begin{aligned} \text{Mutual Inductance} &= \frac{\Phi_m}{I} \\ &\rightarrow \frac{\iint \mathbf{B} \cdot d\mathbf{S} / L}{\oint \mathbf{B} \cdot d\mathbf{\ell}} \rightarrow \frac{\iint \mathbf{B} \cdot d\mathbf{S} / L}{i\omega\mu_0\epsilon \iint \mathbf{E} \cdot d\mathbf{A}} \end{aligned}$$

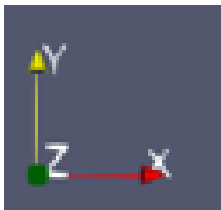
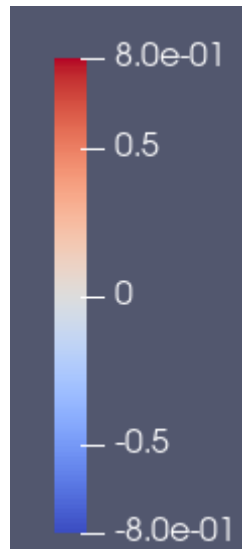
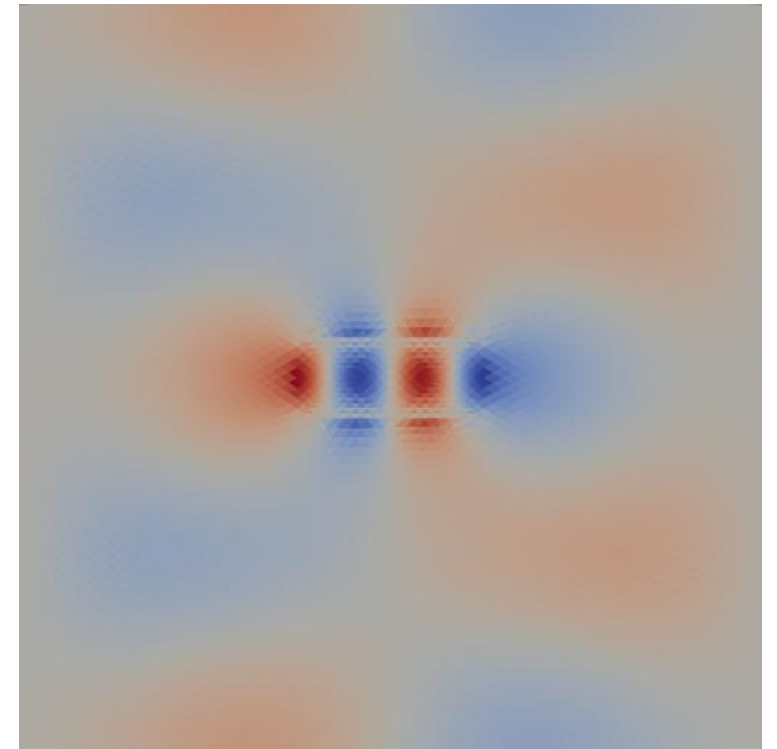
Analytic Inductance: 5.394449e-07

$$\nabla \times \nabla \times E = k^2 \epsilon E$$

X component



Y component



# MFEEM

# Thank-you



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